



SBT20150LFCT

ULTRA LOW VF SCHOTTKY RECTIFIER

VOLTAGE

CURRENT 20 Ampere

FEATURES

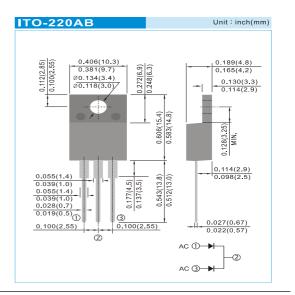
• Ultra low forward voltage drop, low power loss

150 Volt

- High efficiency operation
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. . (Halogen Free)

MECHANICAL DATA

- Case : ITO-220AB, Plastic
- Terminals : Solderable per MIL-STD-750, Method 2026
- Weight : 0.056 ounces, 1.6 grams.



MAXIMUM RATINGS(TA=25°C unless otherwise noted)

PARAMETER		SYMBOL	VALUE	UNIT
Maximum repetitive peak reverse voltage		Vrrm	150	V
Maximum rms voltage		Vrms	105	V
Maximum dc blocking voltage		VR	150	V
Maximum average forward rectified current	per device per diode	I F(AV)	20 10	А
Peak forward surge current : 8.3ms single half sine-wave superimposed on rated load		I FSM	150	А
Typical thermal resistance	(Note 1)	Rejc	9	°C/W
Operating junction temperature range		TJ	-55 to + 150	°C
Storage temperature range		Тѕтс	-55 to + 150	°C

Note : 1. Device mounted on a infinite heatsink.

ELECTRICAL CHARACTERISTICS(TA=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Breakdown voltage per diode	Vbr	I R=0.5mA	TJ=25°C	150	-	-	V
Instantaneous forward voltage per diode	Vf	I F=1A I F=5A I F=10A I F=1A	TJ=25℃	- -	0.54 0.72 0.8 0.44	- - 0.85	v
		I F=TA I F=5A	TJ=125℃	-	0.44 0.59	-	V
Reverse current per diode		Vr=105V	TJ=25℃	-	1.5	-	μΑ
	l r	Vr=150V	TJ=25°C TJ=125°C	-	- 3	40	μA mA

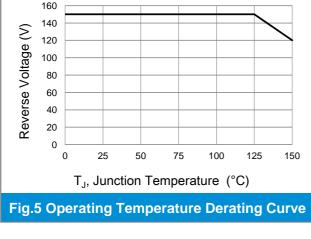




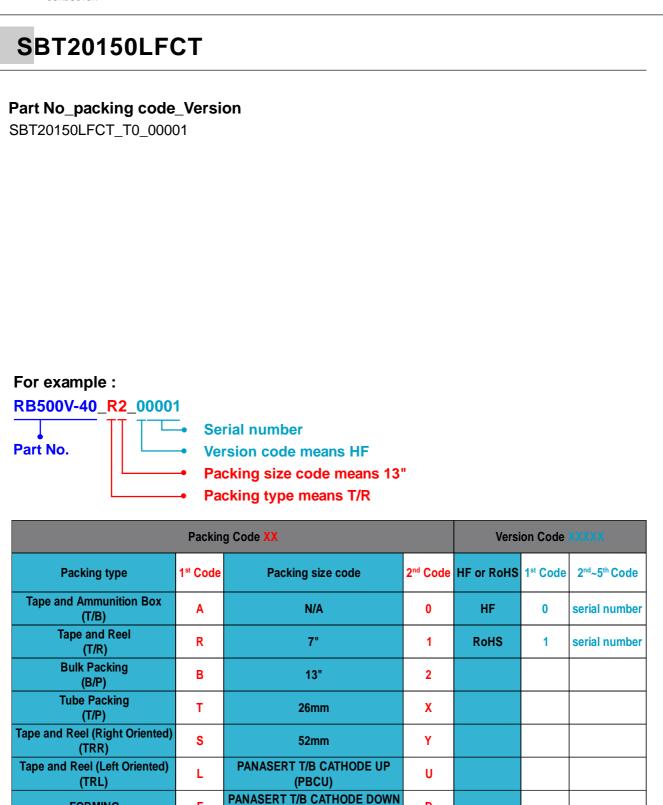
100

1.5

SBT20150LFCT 12.5 1000 C_J, Junction Capacitance (pF) I_F, Forward Current (A) 10 100 7.5 5 10 2.5 per diode per diode 0 1 50 150 75 100 125 0 25 10 V_R, Reverse Bias Voltage (V) T_C, Case Temperature (°C) **Fig.1 Forward Current Derating Curve Fig.2 Typical Junction Capacitance** 10 100 Reverse Current (mA) I_F, Forward Current (A) T_J = 150°C 1 T₁= 125°C T₁ = 150°C 10 T_J = 125°C 0.1 T.I = 75°C 1 T_J = 75°C 0.01 per diode T₁ = 25°C 0.1 0.001 T_J = 25°C per diode 0.0001 0.01 20 30 40 50 60 70 80 90 100 0 0.5 1 Percent of Rated Peak Reverse Voltage (%) V_F, Forward Voltage (V) **Fig.3 Typical Reverse Characteristics Fig.4 Typical Forward Characteristics** 160







(PBCD)

D

FORMING

F





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